

Amir Dastgheib-Shirazi

List of Publications by Year in descending order

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14
papers

277
citations

1163117

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1372567

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14
all docs

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docs citations

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times ranked

359
citing authors

| # | ARTICLE | IF | CITATIONS |
|----|---|-----|-----------|
| 1 | A numerical simulation study of gallium-phosphide/silicon heterojunction passivated emitter and rear solar cells. Journal of Applied Physics, 2014, 115, 044508. | 2.5 | 49 |
| 2 | Relationships between Diffusion Parameters and Phosphorus Precipitation during the POCl ₃ Diffusion Process. Energy Procedia, 2013, 38, 254-262. | 1.8 | 45 |
| 3 | Optimizing phosphorus diffusion for photovoltaic applications: Peak doping, inactive phosphorus, gettering, and contact formation. Journal of Applied Physics, 2016, 119, . | 2.5 | 45 |
| 4 | Heavily doped Si:P emitters of crystalline Si solar cells: recombination due to phosphorus precipitation. Physica Status Solidi - Rapid Research Letters, 2014, 8, 680-684. | 2.4 | 36 |
| 5 | Minimizing the electrical losses on the front side: Development of a selective emitter process from a single diffusion. , 2008, , . | | 25 |
| 6 | Limitation of Industrial Phosphorus-diffused Emitters by SRH Recombination. Energy Procedia, 2014, 55, 115-120. | 1.8 | 21 |
| 7 | A model for phosphosilicate glass deposition via POCl ₃ for control of phosphorus dose in Si. Journal of Applied Physics, 2012, 112, 124912. | 2.5 | 18 |
| 8 | Impact of Extended Contact Cofiring on Multicrystalline Silicon Solar Cell Parameters. IEEE Journal of Photovoltaics, 2017, 7, 91-96. | 2.5 | 17 |
| 9 | Dissolution of Electrically Inactive Phosphorus by Low Temperature Annealing. Energy Procedia, 2015, 77, 286-290. | 1.8 | 9 |
| 10 | Analyzing emitter dopant inhomogeneities at textured Si surfaces by using 3D process and device simulations in combination with SEM imaging. , 2012, , . | | 8 |
| 11 | Electrically-inactive phosphorus re-distribution during low temperature annealing. Journal of Applied Physics, 2018, 123, 161535. | 2.5 | 3 |
| 12 | Enhanced Oxidation of Thermally Grown SiO ₂ Due to P Precipitates. Energy Procedia, 2016, 92, 457-465. | 1.8 | 1 |
| 13 | Role of thermal SiO ₂ on passivation of highly doped layer. AIP Conference Proceedings, 2019, , . | 0.4 | 0 |
| 14 | A novel approach for the evaluation of a phosphorus diffusion design of experiment. AIP Conference Proceedings, 2019, , . | 0.4 | 0 |